

Datasheet

M.2 (P80) 3TG6-P series

- PCIe Gen. III x4, NVMe 1.3
- Excellent data transfer speed
- Stable sustained performance
- Heat-spreading design
- LDPC ECC engine supported.



Introduction

Innodisk M.2 (P80) 3TG6-P is an NVM Express SSD designed as the standard M.2 form factor with PCIe interface and 3D TLC NAND Flash. M.2 (P80)3TG6-P supports PCIe Gen III x4, and it is compliant with NVMe 1.3 providing excellent performance. M.2 (P80) 3TG6-P with heat-spreading design dissipate heat generating from IC making SSD perform more steady. M.2 (P80) 3TG6-P have Die RAID protection to reduce bad blocks happening and optimize data integrity.

Innodisk M.2 (P80) 3TG6-P provides ultra-speed and high IOPS and offers maximum capacity up to 2TB, making the SSD optimal for server and heavy data workload applications.

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M.2 (P80) 3TG6-P series

Contact us for more information
about the M2 (P80) 3TG6-P.

Innodisk is a service-driven provider of industrial embedded flash and DRAM storage products and technologies, with a focus on the cloud computing, industrial/embedded, and aerospace and defense industries.

Headquarters (Taiwan)

5F., No. 237, Sec. 1, Datong Rd., Xizhi
Dist., New Taipei City 221, Taiwan
Tel: +886-2-7703-3000
Email: sales@innodisk.com

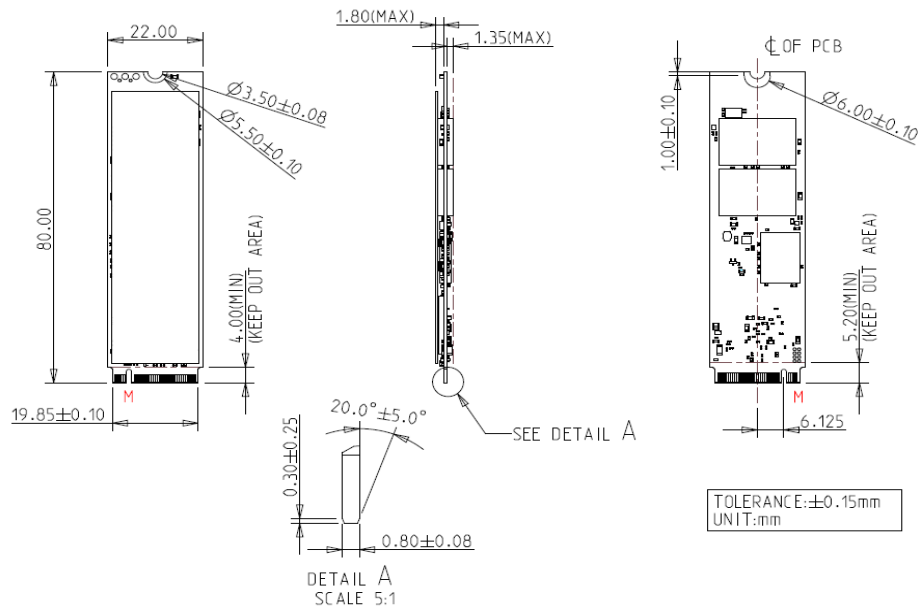
Branch Offices:

USA
usales@innodisk.com
+1-510-770-9421
Europe
eusales@innodisk.com
+31-40-3045-400
Japan
jpsales@innodisk.com
+81-3-6667-0161
China
sales_cn@innodisk.com
+86-755-21673689
www.innodisk.com

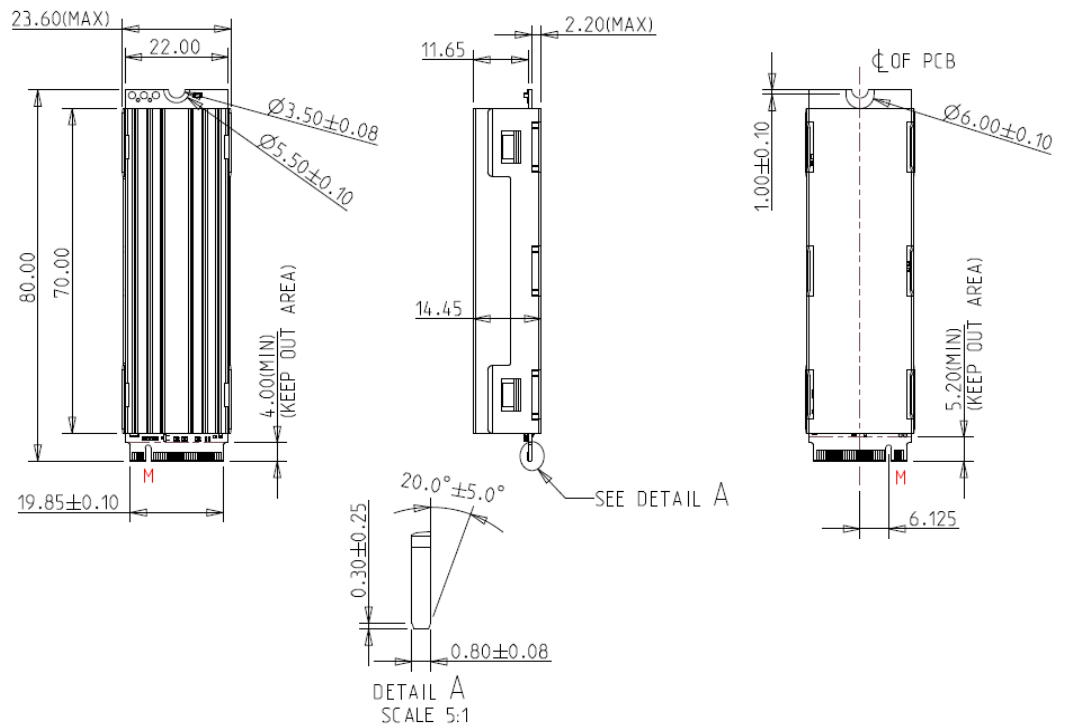
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Diagram(ST)



Diagram(WT)



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M.2 (P80)

3TG6-P series

Diagram(ST)

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Email: sales@innodisk.com

Branch Offices:

USA
usasales@innodisk.com
+1-510-770-9421
Europe
eusales@innodisk.com
+31-40-3045-400
Japan
jpsales@innodisk.com
+81-3-6667-0161
China
sales_cn@innodisk.com
+86-755-21673689
www.innodisk.com

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Interface	PCIe Gen. III x4
Flash Type	3D TLC
P/E cycle	3,000
Capacity	64GB~2TB
Max. Channels	8
Sequential R/W (MB/sec, max.)	3,500/2,600
Max. Power Consumption	6.0W
Thermal Sensor	✓
External DRAM buffer	✓
H/W Write Protect	NA
Dimension (WxLxH)	ST with heat-spreading copper layer: 22.0 X 80.0 X 3.95 mm WT with heatsink: 23.6 X 80.0 X 14.45 mm (Pure M.2: 22.0 X 80.0 X 3.5 mm)
Environment	Vibration: 20G @ 7~2000Hz Shock: 1500G @ 0.5ms Storage Temperature: -40°C ~ +85°C MTBF: 3 million hours

Ordering Information

Operation Temp.	64GB	128GB	256GB	512GB	1TB	2TB
Standard Grade (0°C ~ +70°C)	DGM28- 64GDC1ECADF	DGM28- A28DC1 #CA%F	DGM28- B56DC1 #CA%F	DGM28- C12DC1 #CAEF	DGM28- 01TDC1 #CAEF	DGM28- 02TDC1GCAEF
Industrial Grade (-40°C ~ +85°C)	DGM28- 64GDC1EWADFH	DGM28- A28DC1EWAQFH	DGM28- B56DC1EWAEFH	DGM28- C12DC1EWAEFH	DGM28- 01TDC1EWAEFH	NA

%. D: Dual channels / Q: four channels / E: eight channels
#. E: 64 layers 3D TLC / G: 96 layers 3D TLC

